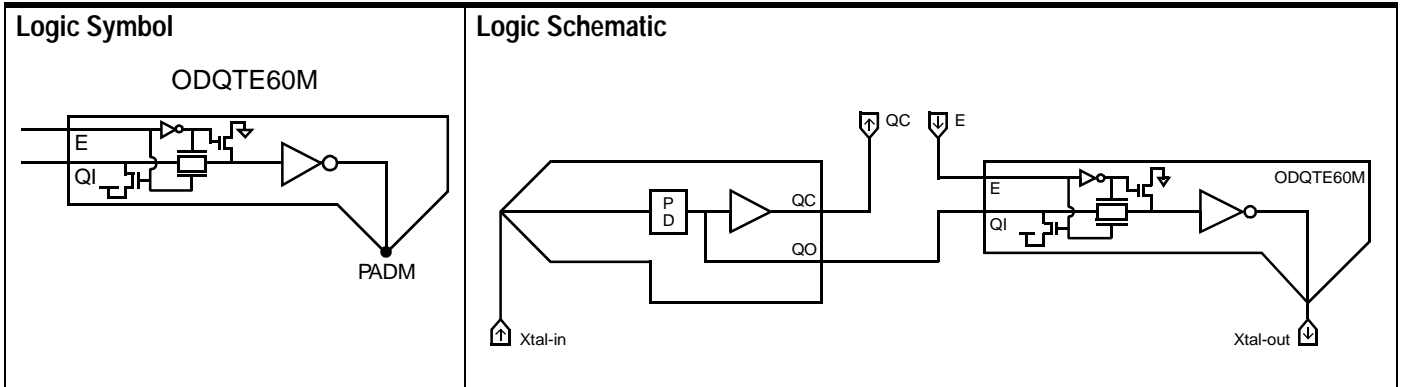


## AMI5HG 0.5 micron CMOS Gate Array

### Description

ODQTE60M is an enabled crystal oscillator, output driver pad piece that runs over a frequency range of 20 - 60 MHz. QI is the input from the IDQC3. E is the oscillator high input enable. PADM is the bond pad to Xtal-out.



Truth Table		
PADM	E	QI
H	L	X
H	H	L
L	H	H

Pin Loading	
	Load
E	6.5 eql
QI	5.5 eql

Pad Loading

### HDL Syntax

Verilog ..... ODQTE60M *inst\_name* (PADM, E, QI);  
 VHDL ..... *inst\_name*: ODQTE60M port map (PADM, E, QI);

### Power Characteristics

Parameter	Value	Units
Static I <sub>DD</sub> (T <sub>J</sub> = 85°C)	TBD	nA
EQL <sub>pd</sub>	176.1	Eq-load

See page 2-15 for power equation.

## AMI5HG 0.5 micron CMOS Gate Array

### Propagation Delays

Conditions:  $T_J = 25^\circ\text{C}$ ,  $V_{DD} = 5.0\text{V}$ , Typical Process

From	Delay (ns)	To	Parameter	Capacitive Load (pF)				
				15	50	100	200	300 (max)
E		PADM	$t_{PLH}$	2.78	4.63	7.29	12.61	17.93
			$t_{PHL}$	1.53	3.37	6.01	11.28	16.57
QI		PADM	$t_{PLH}$	1.53	3.38	6.03	11.33	16.64
			$t_{PHL}$	1.54	3.43	6.06	11.30	16.60

Delay will vary with input conditions. See page 2-17 for interconnect estimates.

### Design Notes:

The ODQTE60M is the output cell of a two cell oscillator circuit. The QI pin is to be connected the QO pin of the IDQC3 oscillator input receiver piece. Two package pins are required to create a complete oscillator.